TOSHIBA Transistor Silicon NPN Triple Diffused Type

# 2SC3405

Switching Regulator and High Voltage Switching Applications

High Speed DC-DC Converter Applications

• Excellent switching times:  $t_r = 1.0 \ \mu s \ (max)$ 

 $t_f = 1.0 \ \mu s \ (max), \ (I_C = 0.3 \ A)$ 

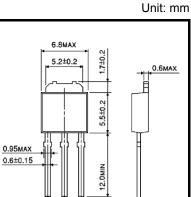
• High collector breakdown voltage:  $V_{CEO} = 800 \text{ V}$ 

#### Absolute Maximum Ratings (Ta = 25°C)

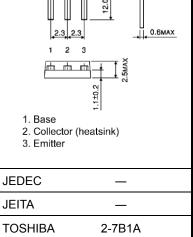
Characteristics		Symbol	Rating	Unit	
Collector-base voltage		V <sub>CBO</sub>	900	V	
Collector-emitter voltage		V <sub>CEO</sub>	800	V	
Emitter-base voltage		V <sub>EBO</sub>	8	V	
Collector current	DC	Ι <sub>C</sub>	0.8	A	
	Pulse	I <sub>CP</sub>	1.5		
Base current		Ι <sub>Β</sub>	0.2	А	
Collector power dissipation	Ta = 25°C	Pc	1.0	W	
	Tc = 25°C	FC	20		
Junction temperature		Тј	150	°C	
Storage temperature range		T <sub>stg</sub>	−55 to 150	°C	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

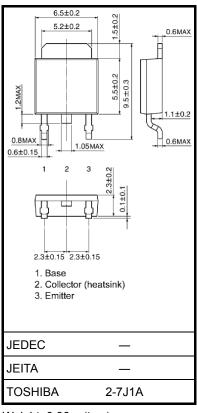
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).



Industrial Applications



#### Weight: 0.36 g (typ.)

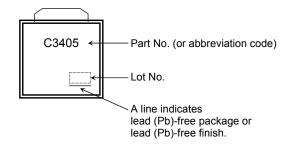


Weight: 0.36 g (typ.)

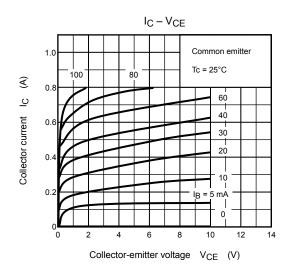
Electrical Characteristics (Ta = 25°C)

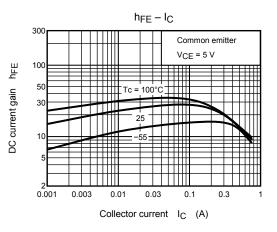
Chara	Characteristics Symbol Test Condition		Min	Тур.	Max	Unit	
Collector cut-off c	urrent	I <sub>CBO</sub>	V <sub>CB</sub> = 800 V, I <sub>E</sub> = 0	—	_	100	μA
Emitter cut-off cur	rrent	I <sub>EBO</sub>	V <sub>EB</sub> = 8 V, I <sub>C</sub> = 0	_	_	1	mA
Collector-base bro	eakdown voltage	V (BR) CBO	I <sub>C</sub> = 1 mA, I <sub>E</sub> = 0	900	_	_	V
Collector-emitter	breakdown voltage	V (BR) CEO	I <sub>C</sub> = 10 mA, I <sub>B</sub> = 0	800	_	_	V
DC current gain		h <sub>FE</sub>	V <sub>CE</sub> = 5 V, I <sub>C</sub> = 1 mA	6			
			V <sub>CE</sub> = 5 V, I <sub>C</sub> = 0.3 A	10	_	-	
Collector-emitter	saturation voltage	V <sub>CE (sat)</sub>	I <sub>C</sub> = 0.3 A, I <sub>B</sub> = 0.06 A	_	_	0.5	V
Base-emitter saturation voltage		V <sub>BE (sat)</sub>	I <sub>C</sub> = 0.3 A, I <sub>B</sub> = 0.06 A	_	_	1.2	V
Switching time	Rise time	tr	$20 \ \mu s \qquad  B1 \qquad OUTPUT \\ \downarrow \square \qquad \square$	_	_	1.0	μs
	Storage time	t <sub>stg</sub>		_	_	4.0	
	Fall time	t <sub>f</sub>	I <sub>B1</sub> = −I <sub>B2</sub> = 0.06 A, DUTY CYCLE ≤ 1%	_	_	1.0	

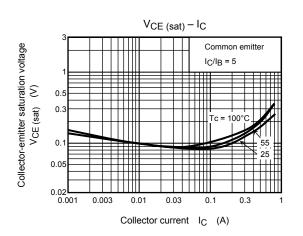
### Marking

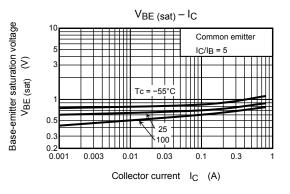


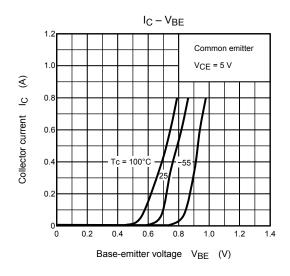
## TOSHIBA

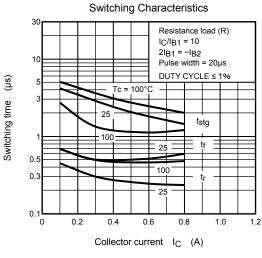






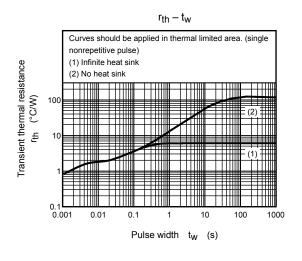


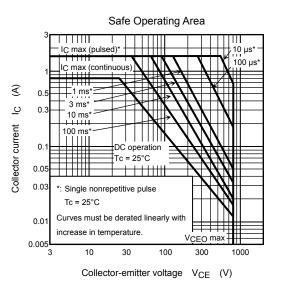






## <u>TOSHIBA</u>





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